



100V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D T _C = +25°C (Note 5)
100\/	8.8mΩ @ V _G S = 10V	100A
100V	11.5mΩ @ V _{GS} = 6V	100A

Description

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP.

Applications

- Motor controls
- DC-DC converters
- Power managements

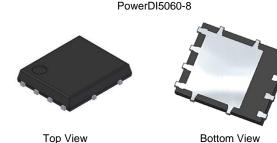
Features

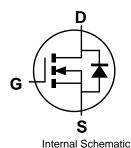
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low R_{DS(ON)} Minimizes On-State Losses
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH10H010SPSQ is suitable for automotive applications requiring specific change control; This part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

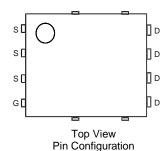
https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminal Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208@3
- Weight: 0.097 grams (Approximate)







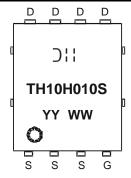
Ordering Information (Note 4)

Part Number	Dookers	Packing		
Part Number	Package	Qty.	Carrier	
DMTH10H010SPSQ-13	PowerDI5060-8	2,500	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.
- Package limited.

Marking Information



☐ I = Manufacturer's Marking
TH10H010S = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 24 = 2024)
WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V_{DSS}	100	V	
Gate-Source Voltage	Vgss	±20	V	
Continuous Drain Current, V _{GS} = 10V (Note 6)	$T_A = +25^{\circ}C$ $T_A = +100^{\circ}C$	ID	15 11	Α
Continuous Drain Current, V _{GS} = 10V (Note 7)	$T_{C} = +25^{\circ}C$ (Note 5) $T_{C} = +100^{\circ}C$	lo	100 87	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	250	Α	
Maximum Continuous Body Diode Forward Current	Is	100	Α	
Avalanche Current, L = 0.3mH	las	25	Α	
Avalanche Energy, L = 0.3mH	Eas	93.7	mJ	
Avalanche Current (Note 8), L = 3mH		las	14.3	Α
Avalanche Energy (Note 8), L = 3mH		E _{AS}	307	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 6)	$T_A = +25$ °C	PD	3	W
Thermal Resistance, Junction to Ambient (Note 6)		Reja	49	°C/W
Total Power Dissipation (Note 7) $T_C = +25^{\circ}C$		P _D	166	W
Thermal Resistance, Junction to Case (Note 7)		Reлc	0.9	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

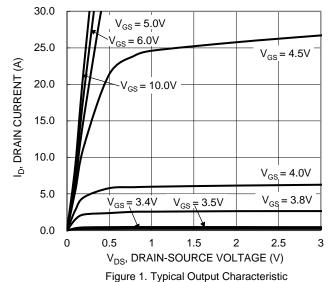
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)					•		
Drain-Source Breakdown Voltage	BVDSS	100	_	_	V	$V_{GS} = 0V$, $I_{D} = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	Igss		_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	Vgs(th)	2	_	4	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Ctatia Duain Causas On Desistance		_	6.6	8.8	mΩ	Vgs = 10V, ID = 13A	
Static Drain-Source On-Resistance	R _{DS(ON)}		8.5	11.5	mt2	$V_{GS} = 6V, I_D = 13A$	
Diode Forward Voltage	VsD		0.8	1.3	V	Vgs = 0V, Is = 13A	
DYNAMIC CHARACTERISTICS (Note 8)					•		
Input Capacitance	Ciss	_	4468	_		V _{DS} = 50V, V _{GS} = 0V f = 1MHz	
Output Capacitance	Coss	_	746	_	pF		
Reverse Transfer Capacitance	Crss		32	_			
Gate Resistance	Rg		0.91	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg		56.4			V _{DD} = 50V, I _D = 13A, V _{GS} = 10V	
Gate-Source Charge	Qgs	_	15.4	_	nC		
Gate-Drain Charge	Qgd		14				
Turn-On Delay Time	t _{D(ON)}	_	18.6	_		$V_{DD} = 50V$, $V_{GS} = 10V$, $I_{D} = 13A$, $R_{g} = 6\Omega$	
Turn-On Rise Time	t _R		22.5	_	İ		
Turn-Off Delay Time	t _{D(OFF)}	_	44.8	_	ns		
Turn-Off Fall Time	t _F	_	29.5	_	1	-	
Reverse Recovery Time	trr	_	54.5	_	ns	104 11/11 1004/	
Reverse Recovery Charge	Q _{RR}	_	106.4	_	$_{\rm nC}$ I _F = 13A, di/dt = 100A/µs		

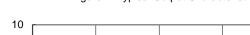
Notes: 5. Package limited

- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
- 7. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 8. Guaranteed by design. Not subject to product testing.
- 9. Short duration pulse test used to minimize self-heating effect.









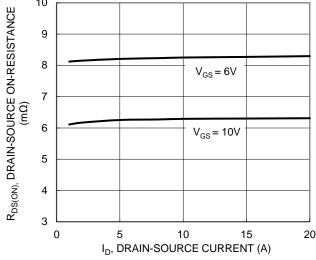


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

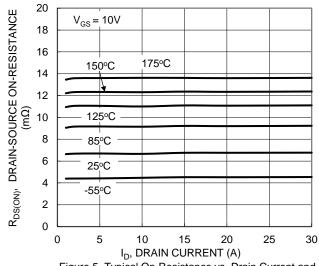


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

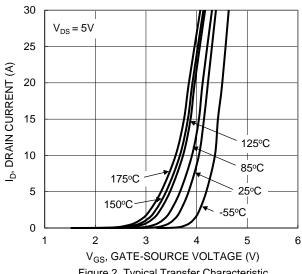


Figure 2. Typical Transfer Characteristic

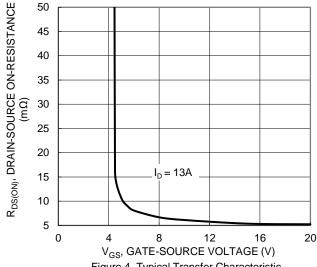


Figure 4. Typical Transfer Characteristic

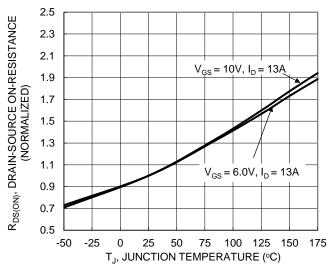


Figure 6. On-Resistance Variation with Junction Temperature





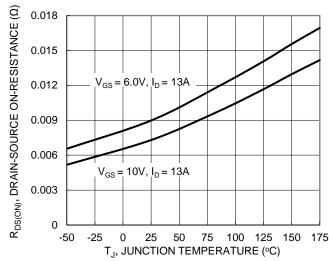


Figure 7. On-Resistance Variation with Junction Temperature

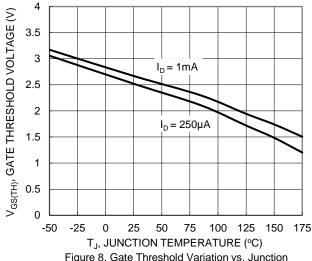


Figure 8. Gate Threshold Variation vs. Junction Temperature

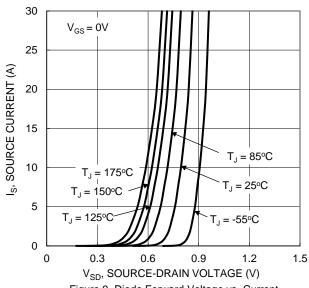
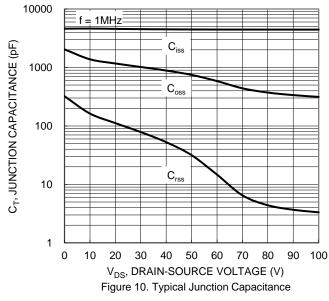
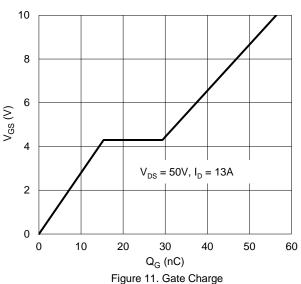
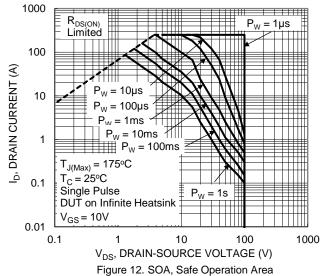


Figure 9. Diode Forward Voltage vs. Current









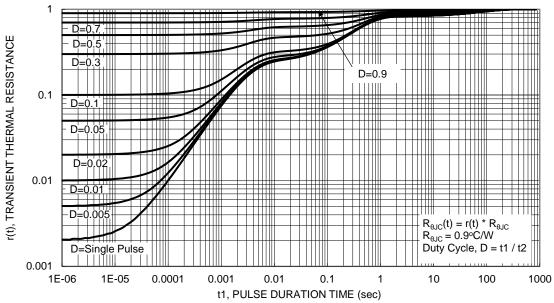


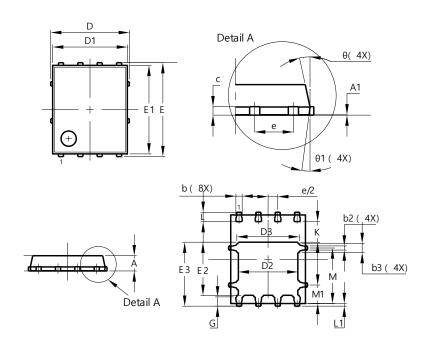
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

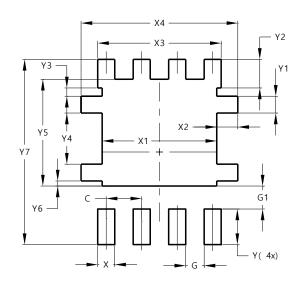


PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
C	0.230	0.330	0.277		
D	5.15 BSC				
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	-	-		
٦	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)			
C	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Υ	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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